NSN 5961-01-014-8153

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-8153 **Inclosure Material:** Ceramic **Overall Length:** 20.0 millimeters **Terminal Length:** 1.5 millimeters **Overall Diameter:** 5.0 millimeters **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 pin and 1 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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